



## QL78D6S-A/B/C

AlGaAs Laser Diode

Ver.0 JAN 2004

### ◆ OVERVIEW

**QL78D6S-A/B/C** is a MOCVD grown 780nm band AlGaAs laser diode with quantum well structure. It's an attractive light source, with a typical light output power of 5mW for industrial optical module and sensor applications.

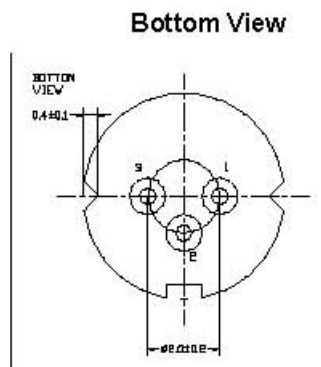
### ◆ APPLICATION

- CD-P

### ◆ FEATURES

- Lasing Wavelength :  $\lambda_p = 780\text{nm}$
- Optical Power Output : 5mW CW
- Package Type : TO-18 (5.6mm $\Phi$ )
- Built-in Photo Diode for Monitoring Laser Output

### ◆ ELECTRICAL CONNECTION



Pin Configuration

|   |                               |
|---|-------------------------------|
| A | LD cathode, PD anode (Fig. 1) |
| B | LD, PD anode (Fig. 2)         |
| C | LD anode, PD cathode (Fig. 3) |

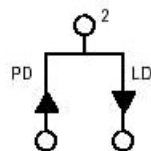


Fig. 1  
QL78D6SA

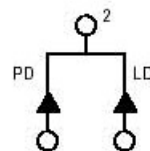


Fig. 2  
QL78D6SB

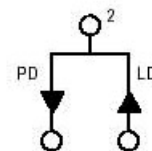


Fig. 3  
QL78D6SC



## ◆ ABSOLUTE MAXIMUM RATING

| Items                       | Symbols          | Values    | Unit |
|-----------------------------|------------------|-----------|------|
| Optical Output Power        | P                | 6         | mW   |
| Laser Diode Reverse Voltage | V                | 2         | V    |
| Photo Diode Reverse Voltage | V                | 30        | V    |
| Operating Temperature       | T <sub>opr</sub> | -10 ~ +60 | °C   |
| Storage Temperature         | T <sub>stg</sub> | -40 ~ +80 | °C   |

## ◆ ELECTRICAL and OPTICAL CHARACTERISTICS

| Items                | Symbols         | Min. | Typ. | Max. | Unit  | Condition               |
|----------------------|-----------------|------|------|------|-------|-------------------------|
| Optical Output Power | P <sub>o</sub>  | -    | 5    | -    | mW    | -                       |
| Threshold Current    | I <sub>th</sub> | -    | 20   | 30   | mA    | -                       |
| Operating Current    | I <sub>op</sub> | -    | 30   | 40   | mA    | P <sub>o</sub> =5mW     |
| Operating Voltage    | V <sub>op</sub> | -    | 1.9  | 2.3  | V     | P <sub>o</sub> =5mW     |
| Slope Efficiency     | SE              | 0.3  | 0.5  | 0.7  | mW/mA | P <sub>o</sub> =3 ~ 5mW |
| Lasing Wavelength    | λ <sub>p</sub>  | 770  | 785  | 800  | nm    | P <sub>o</sub> =5mW     |
| Beam Divergence      | θ <sub>∥</sub>  | 8    | 11   | 15   | deg   | P <sub>o</sub> =5mW     |
|                      | θ <sub>⊥</sub>  | 25   | 34   | 40   | deg   | P <sub>o</sub> =5mW     |
| Beam Angle           | Δθ <sub>∥</sub> | -    | -    | ±1.5 | deg   | P <sub>o</sub> =5mW     |
|                      | Δθ <sub>⊥</sub> | -    | -    | ±2.5 | deg   | P <sub>o</sub> =5mW     |
| Monitor Current      | I <sub>m</sub>  | 0.1  | 0.3  | 0.6  | mA    | P <sub>o</sub> =5mW     |
| Optical Distance     | ΔX, ΔY, ΔZ      | -    | -    | ±60  | μm    | P <sub>o</sub> =5mW     |
| Astigmatism          | A <sub>s</sub>  | -    | -    | 15   | μm    | P <sub>o</sub> =5mW     |

**NOTICE : QL 78D6S-A/B/C to be operated on APC**

**The above product specifications are subject to change without notice.**



## ◆ PACKAGE DIMENSION

